2MHz, Ultra-Low Offset Voltage Operational Amplifier

The HA-5177 is an all bipolar, precision operational amplifier, utilizing Harris dielectric isolation and advance processing techniques. This design features a combination of precision input characteristics, wide bandwidth (2MHz) and high speed (0.8V/μs).

The HA-5177 uses advanced matching techniques and laser trimming to produce low offset voltage (20μV) and low offset voltage drift (0.2μV/^{o}C). This design also features low voltage noise (9.0nV/$\sqrt{Hz}$), low current noise (1.2pA/$\sqrt{Hz}$), nanoamp input currents, and 120dB minimum gain.

These outstanding features along with high CMRR (140dB) and high PSRR (135dB) make this unity gain stable amplifier ideal for high resolution data acquisition systems, precision integrators, and low level transducer amplifiers.

The HA-5177 can be used as a direct replacement for the OP05, OP07, and OP77 while offering higher bandwidth and slew rate. See the HA-5177/883 data sheet for military grade parts and LCC package.

HA-5177
(PDIP, CERDIP)
TOP VIEW

BAL	1	8	BAL
-IN	2	7	V+
+IN	3	6	OUT
V-	4	5	NC
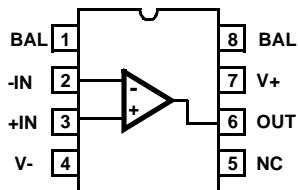
Features

- Low Offset Voltage 20μV
- Low Offset Voltage Drift . . . . 0.2μV/^{o}C
- High Voltage Gain 150dB
- High CMRR 140dB
- High PSRR. 135dB
- Low Noise . . . . 9.0nV/$\sqrt{Hz}$
- Low Power Consumption . . . . .51mW (Max)

Applications

- High Gain Instrumentation Amplifiers
- Precision Control Systems
- Precision Integrators
- High Resolution Data Converters
- Precision Threshold Detectors
- Low Level Transducer Amplifiers

Part Number Information

PART NUMBER	TEMP. RANGE (^{o}C)	PACKAGE	PKG. NO.
HA3-5177-5	0 to 75	8 Ld PDIP	E8.3
HA7-5177-5	0 to 75	8 Ld CERDIP	F8.3A

Absolute Maximum Ratings

Supply Voltage Between V+ and V- Terminals 44V
Differential Input Voltage 7V
Output Current . . . . Short Circuit Protected

Operating Conditions

Temperature Range
  HA-5177-2 . . . . -55°C to 125°C
  HA-5177-5 . . . . 0°C to 75°C

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (^{o}C/W)	θ_{JC} (^{o}C/W)
CERDIP Package.	135	50
PDIP Package	92	N/A

Maximum Junction Temperature (Ceramic Package). . . . . 175°C
Maximum Junction Temperature (Plastic Package) . . . . .150°C
Maximum Storage Temperature Range . . . . -65°C to 150°C
Maximum Lead Temperature (Soldering 10s) . . . . 300°C
  (SOIC - Lead Tips Only)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications $V_{SUPPLY} = \pm15V$, Unless Otherwise Specified

PARAMETER	TEST CONDITIONS	TEMP. (^{o}C)	MIN	TYP	MAX	UNITS
INPUT CHARACTERISTICS						
Offset Voltage		25	-	20	60	μV
		Full	-	40	100	μV
Average Offset Voltage Drift		Full	-	0.2	0.6	μV/^{o}C
Bias Current		25	-	1.2	6	nA
		Full	-	2.4	8	nA
Bias Current Average Drift		Full	-	15	35	pA/^{o}C
Offset Current		25	-	0.6	6	nA
		Full	-	1.0	8	nA
Offset Current Average Drift		Full	-	1.5	50	pA/^{o}C
Common Mode Range		Full	±12	-	-	V
Differential Input Resistance		25	-	47	-	MΩ
Input Noise Voltage	0.1Hz to 10Hz	25	-	0.35	0.6	μV_{P-P}
Input Noise Voltage Density	$f_O = 10$Hz	25	-	13	18	nV/$\sqrt{Hz}$
	$f_O = 100$Hz	25	-	10	13	nV/$\sqrt{Hz}$
	$f_O = 1000$Hz	25	-	9	11	nV/$\sqrt{Hz}$
Input Noise Current	0.1Hz to 10Hz	25	-	14	45	pA$_{P-P}$
Input Noise Current Density	$f_O = 10$Hz	25	-	7.1	10	pA/$\sqrt{Hz}$
	$f_O = 100$Hz	25	-	3.3	5	pA/$\sqrt{Hz}$
	$f_O = 1000$Hz	25	-	1.2	2	pA/$\sqrt{Hz}$
TRANSFER CHARACTERISTICS						
Large Signal Voltage Gain (Note 2)		25	126	150	-	dB
		Full	120	140	-	dB
Common Mode Rejection Ratio (Note 3)		Full	110	140	-	dB
Closed Loop Bandwidth	$A_{VCL} = +1$	25	0.6	2	-	MHz

Electrical Specifications V_{SUPPLY} = ±15V, Unless Otherwise Specified **(Continued)**

PARAMETER	TEST CONDITIONS	TEMP. (°C)	MIN	TYP	MAX	UNITS
OUTPUT CHARACTERISTICS						
Output Voltage Swing	R_L = 600Ω	25	±10	±12.5	-	V
	R_L = 2kΩ	25	±12	±13	-	V
	R_L = 2kΩ	Full	±12	±12.5	-	V
Full Power Bandwidth (Note 5)		25	8	10	-	kHz
Output Current (Note 6)		25	15	20	-	mA
Output Resistance		25	-	60	-	Ω
TRANSIENT RESPONSE						
Rise Time (Note 10)		25	-	310	420	ns
Slew Rate (Note 11)		25	0.5	0.8	-	V/μs
Settling Time (Notes 7, 8)		25	-	14	-	μs
Overshoot (Note 10)		25	-	10	40	%
POWER SUPPLY CHARACTERISTICS						
Supply Current		Full	-	1.2	1.7	mA
Power Supply Rejection Ratio (Note 9)		Full	110	135	-	dB

NOTES:

2. V_{OUT} = ±10V, R_L = 2kΩ.

3. ΔV_{CM} = ±10V.

4. R_L = 2kΩ.

5. Full power bandwidth guaranteed based on slew rate measurement using: FPBW = $\frac{\text{Slew Rate}}{2\pi V_{PEAK}}$; V_{PEAK} = 10V.

6. V_{OUT} = ±10V.

7. Refer to test circuits section of the data sheet.

8. Settling time is measured to 0.1% of final value for a 10V output step and A_V = +1.

9. ΔV_{SUPPLY} = ±10V to ±20V.

10. A_V = 1, R_L = 2kΩ, V_{OUT} = ±200mV.

11. A_V = 1, R_L = 2kΩ, V_{OUT} = 0 to ±3V.

Test Circuits and Waveforms
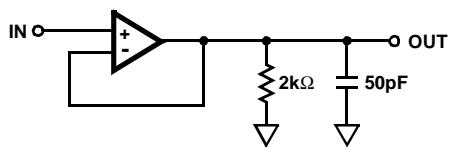
FIGURE 1. SLEW RATE AND TRANSIENT RESPONSE TEST CIRCUIT
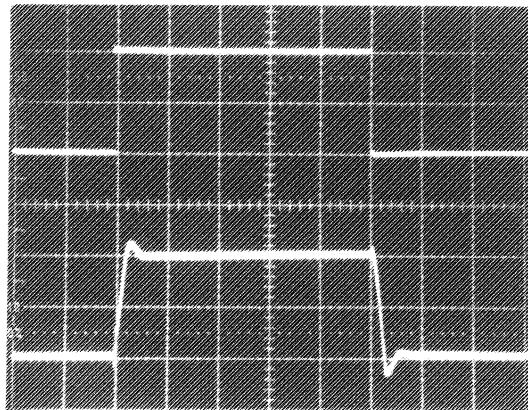
Vertical Scale: 100mV/Div.
Horizontal Scale: 2µs/Div.

FIGURE 2. SMALL SIGNAL RESPONSE
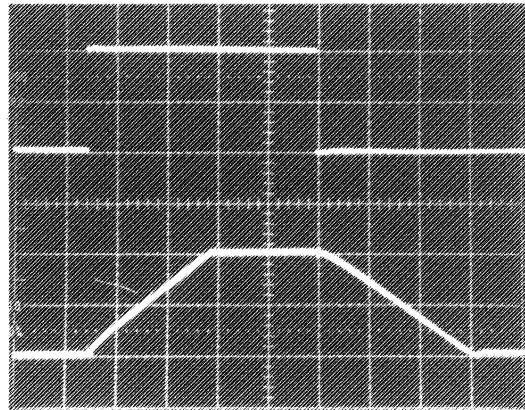
Vertical Scale: 5V/Div.
Horizontal Scale: 5µs/Div.

FIGURE 3. LARGE SIGNAL RESPONSE
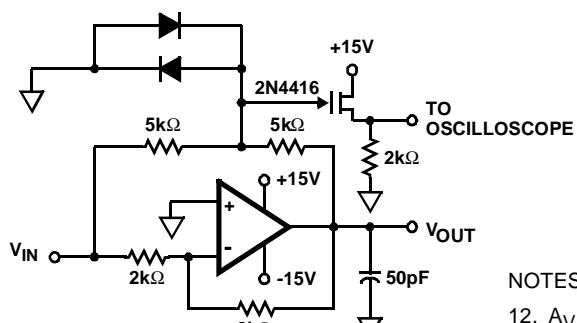
NOTES:

12. $A_V = -1$.

13. Feedback and summing resistors should be 0.1% matched.

14. Clipping diodes are optional. HP5082-2810 recommended.

FIGURE 4. SETTLING TIME CIRCUIT

Schematic Diagram
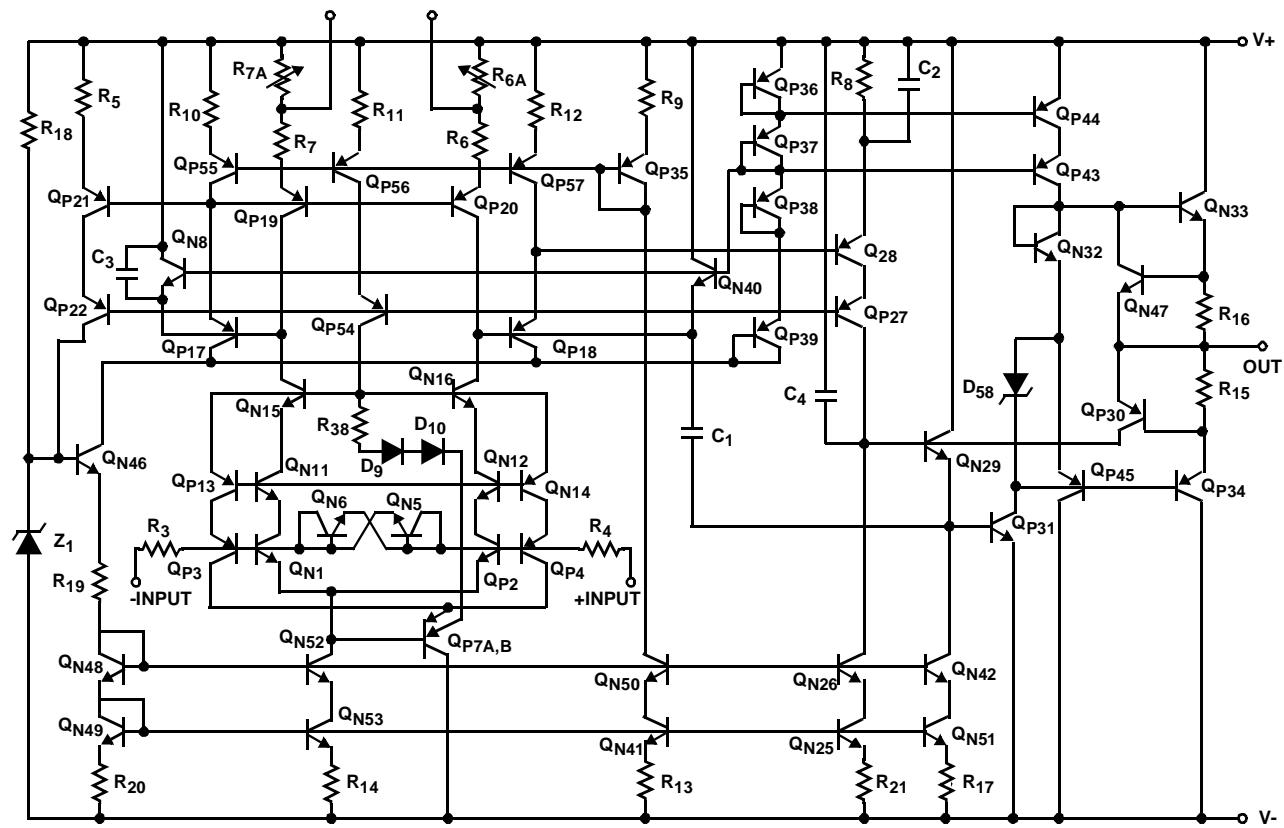
Typical Applications

Operation Below 15V Supply

The HA-5177 performs well down to ±5V supplies. At ±5V supplies there is a slight degradation of slew rate and open loop gain. There is very little change in bias currents and offset voltage.

Offset Adjustment

The following is the recommended V_{IO} adjust configuration:
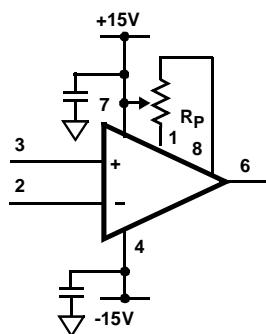
Setting R_P = 20K will give an adjustment range of ±2.6mV.

Input Protection

The HA-5177 input stage has built in back-to-back protection diodes with series current limiting resistors.
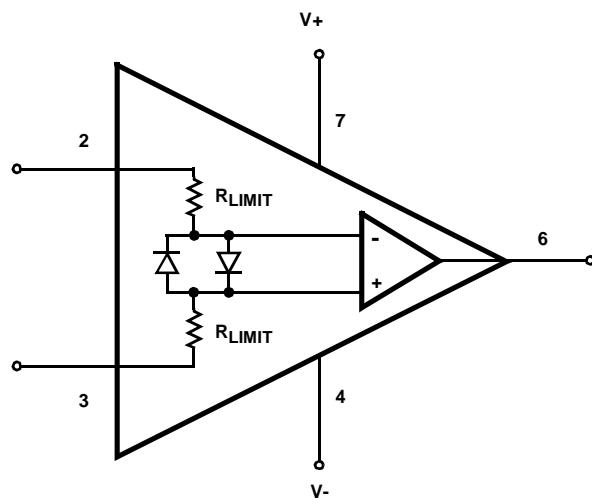
The Bias currents will increase when a differential voltage of 0.7V is exceeded.

The internal current limiting resistors sufficiently limit current therefore, no external resistors are required.

Refer to the ''Bias Current vs Differential Input Voltage'' curve in the Typical Performance Curves.

Typical Performance Curves V_{SUPPLY} = ±15V, T_A = 25°C

FIGURE 5. OPEN LOOP GAIN AND PHASE vs FREQUENCY
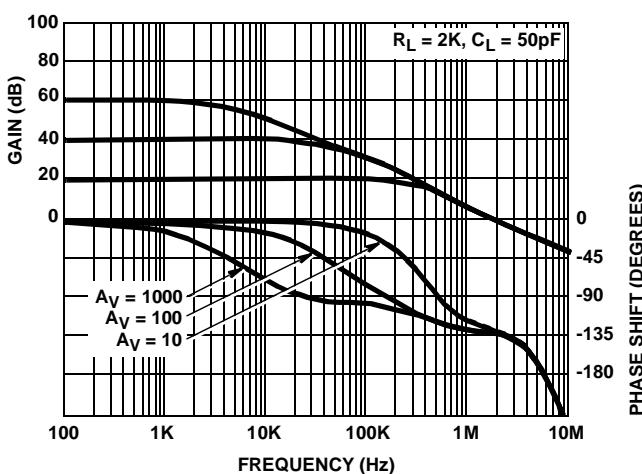
FIGURE 6. VARIOUS CLOSED LOOP GAINS vs FREQUENCY

Typical Performance Curves $V_{SUPPLY} = \pm15V$, $T_A = 25^O C$ **(Continued)**

FIGURE 7. PSRR vs FREQUENCY
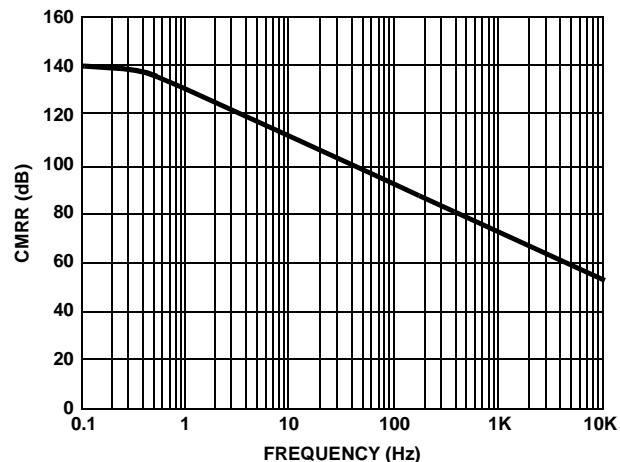
FIGURE 8. CMRR vs FREQUENCY
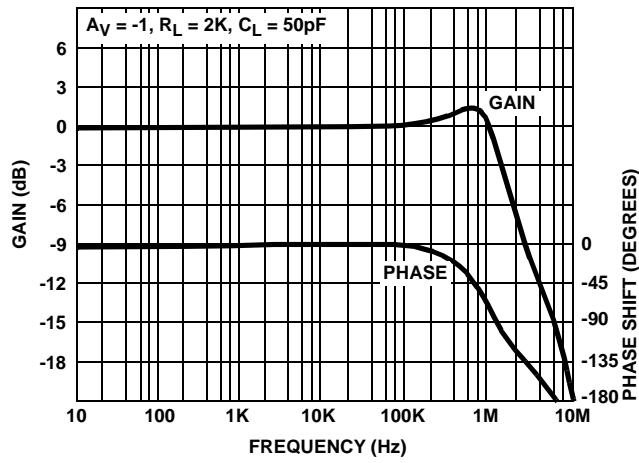
FIGURE 9. CLOSED LOOP GAIN AND PHASE vs FREQUENCY
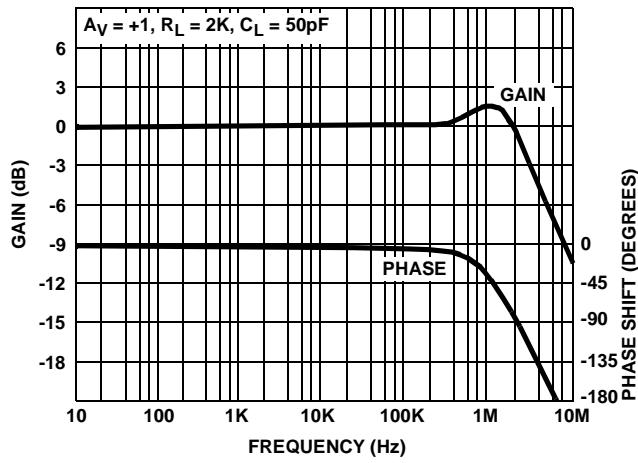
FIGURE 10. CLOSED LOOP GAIN AND PHASE vs FREQUENCY
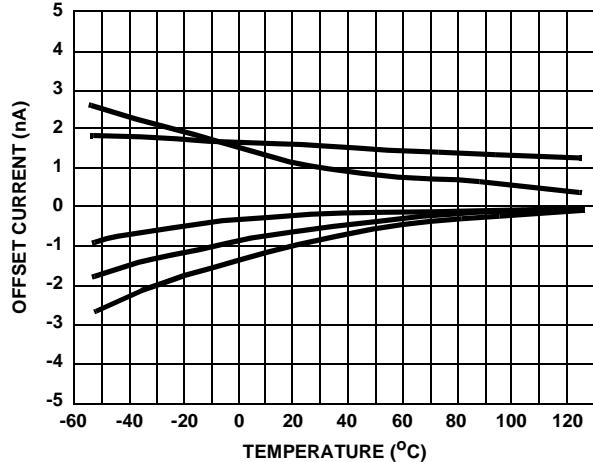
FIGURE 11. OFFSET CURRENT vs TEMPERATURE
(FIVE REPRESENTATIVE UNITS)
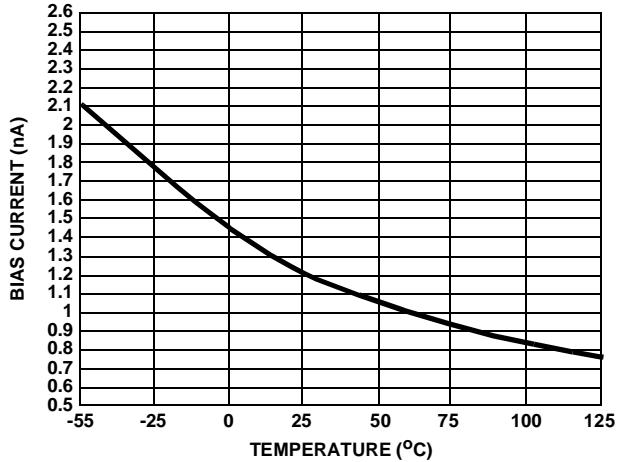
FIGURE 12. BIAS CURRENT vs TEMPERATURE

## *Typical Performance Curves* V~SUPPLY~ = ±15V, T~A~ = 25°C (Continued)
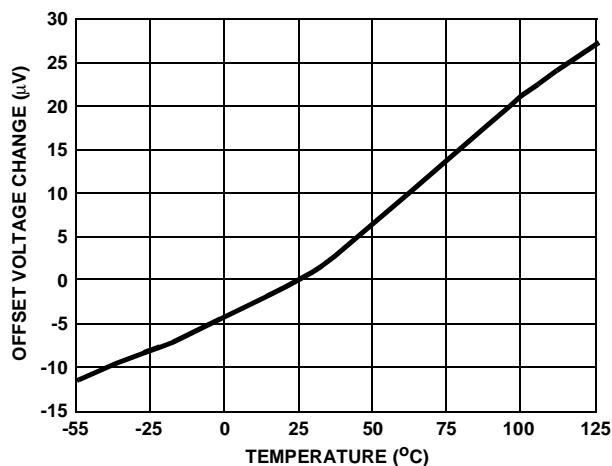
FIGURE 13. OFFSET VOLTAGE vs TEMPERATURE
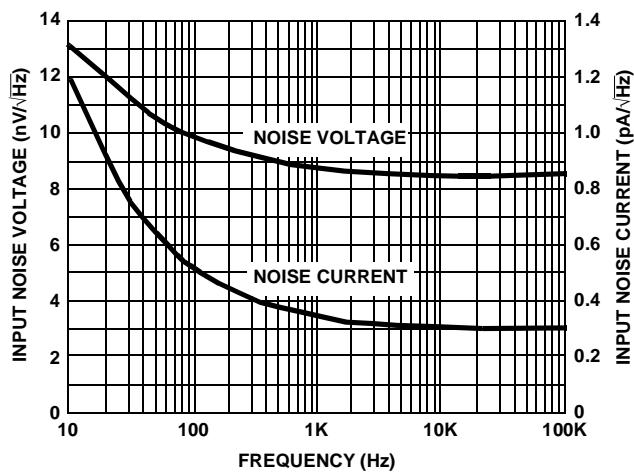
FIGURE 14. INPUT NOISE vs FREQUENCY
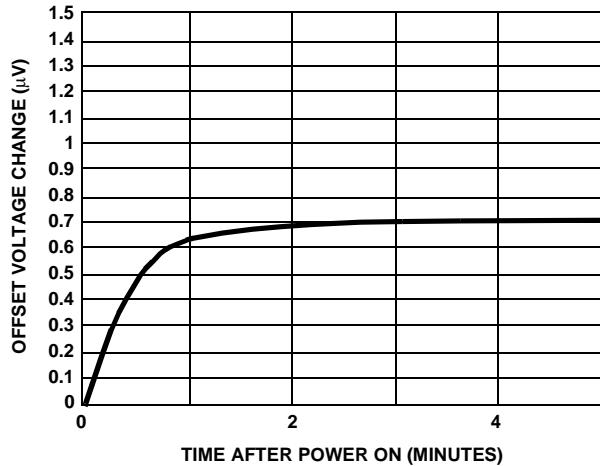
FIGURE 15. OFFSET VOLTAGE WARM-UP DRIFT
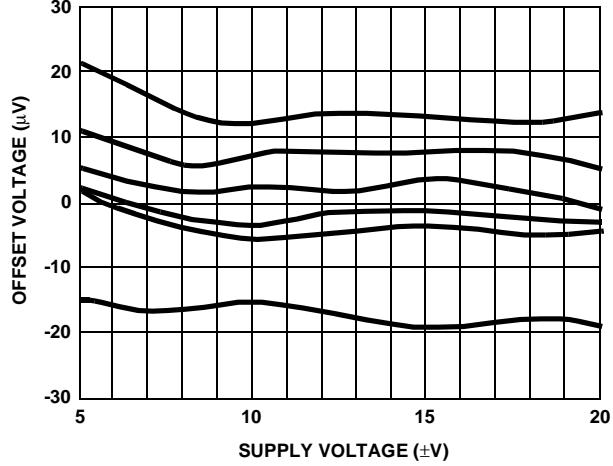
FIGURE 16. OFFSET VOLTAGE vs SUPPLY VOLTAGE
(SIX REPRESENTATIVE UNITS)

Typical Performance Curves $V_{SUPPLY} = \pm 15V$, $T_A = 25^oC$ **(Continued)**
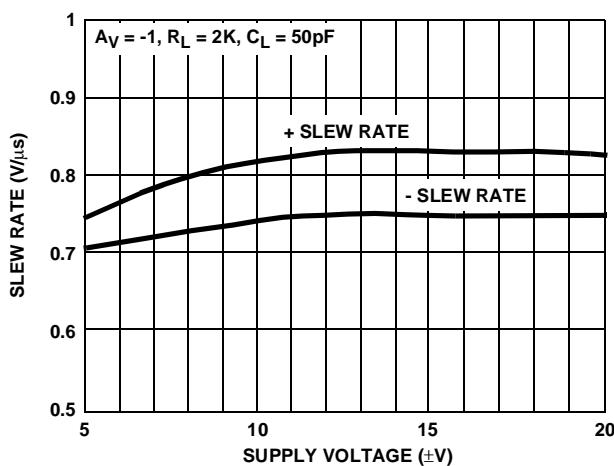
FIGURE 17. SLEW RATE vs. SUPPLY VOLTAGE
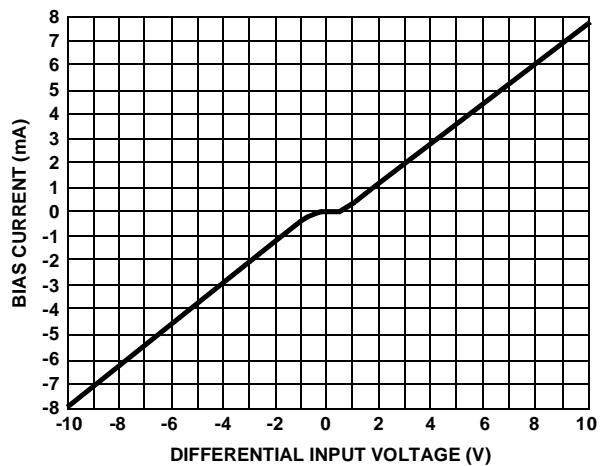
FIGURE 18. BIAS CURRENT vs DIFFERENTIAL INPUT VOLTAGE
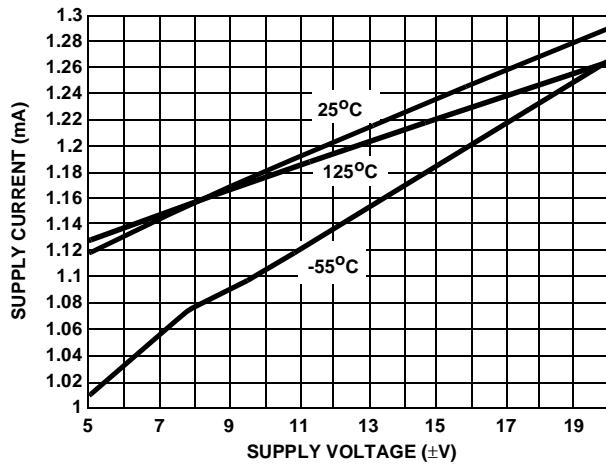
FIGURE 19. SUPPLY CURRENT vs SUPPLY VOLTAGE
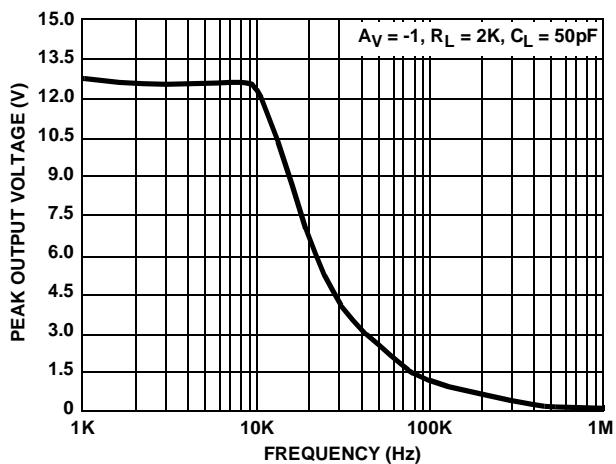
FIGURE 20. OUTPUT VOLTAGE vs FREQUENCY
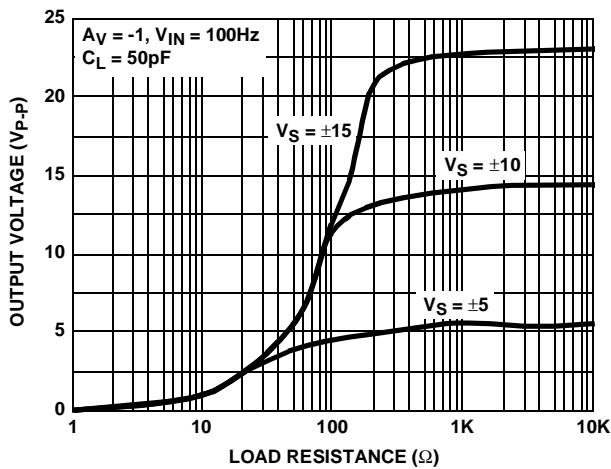
FIGURE 21. OUTPUT VOLTAGE vs LOAD RESISTANCE
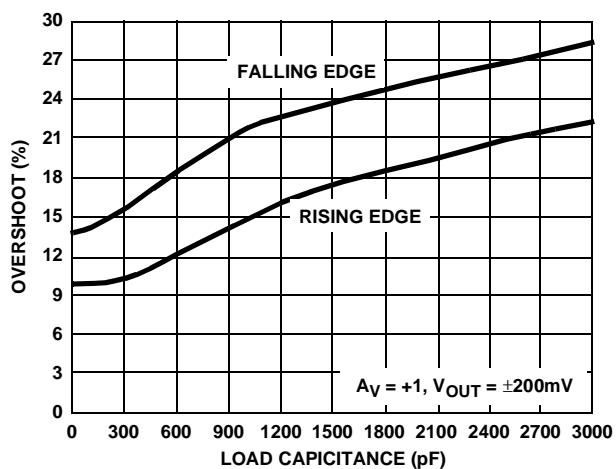
FIGURE 22. OVERSHOOT vs LOAD CAPACITANCE

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## Typical Performance Curves $V_{SUPPLY} = \pm15V$, $T_A = 25^{O}C$ (Continued)

FIGURE 23. SMALL SIGNAL BANDWIDTH AND PHASE MARGIN

$A_V = 25,000$, $E_N = 0.22\mu V_{P-P}$ RTI
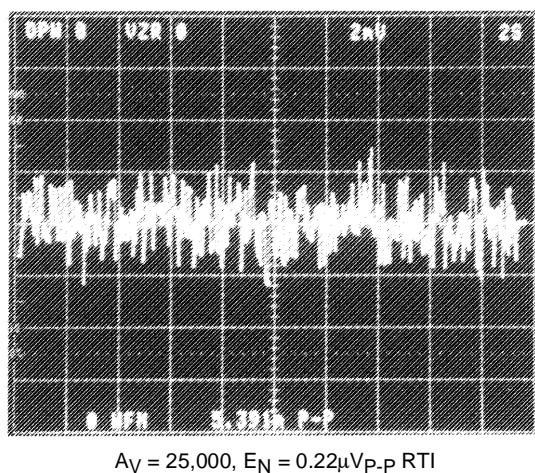
FIGURE 24. PEAK-TO-PEAK NOISE (0.1Hz TO 10Hz)
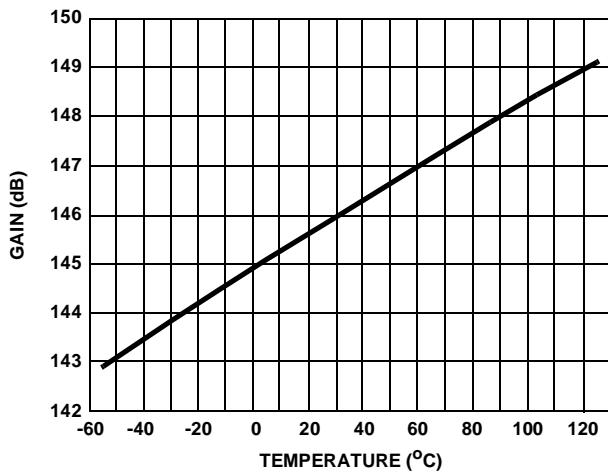

FIGURE 25. OPEN LOOP GAIN vs TEMPERATURE
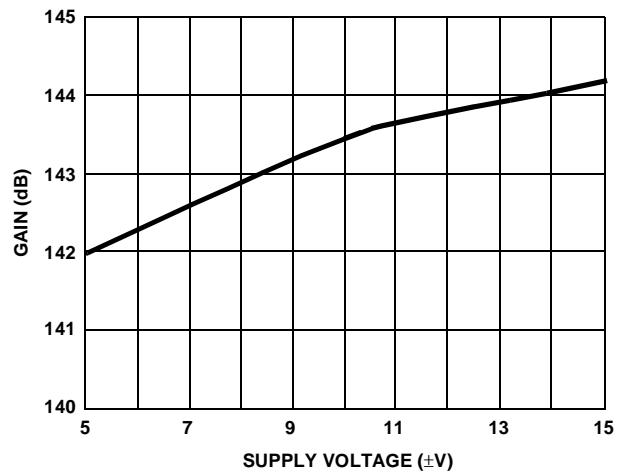
FIGURE 26. OPEN LOOP GAIN vs SUPPLY VOLTAGE
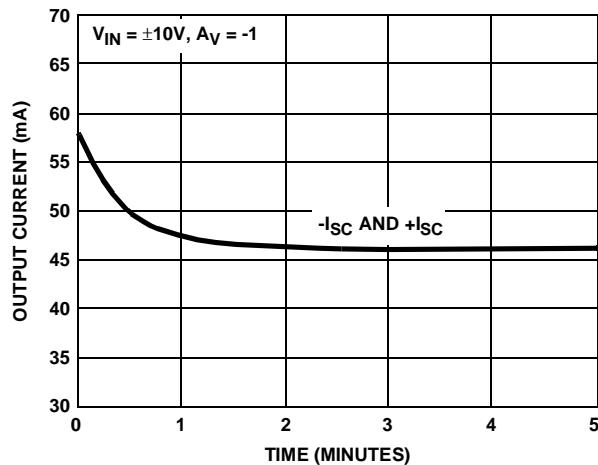
FIGURE 27. OUTPUT SHORT CIRCUIT CURRENT vs TIME